

Fast Recovery Diode

 V_{RRM}

F(AV)

Replaces March 1998 version, DS4153-3.1

DS4153-4.0 January 2000

KEY PARAMETERS

4500V

3230A

20000A 1800μ**C 7.0**μs

APPLICATIONS

■ The DSF21545SV is a purpose designed freewheel diode to complement the DG858BW GTO in inverter circuits, using energy recovery snubbers.

FEATURES

- The DSF21545SV is designed for fast turn-on thus minimising reverse current through the GTO.
- Low recovered charge for low losses.
- DSF21545SV is housed in a similar outline to that of the DG858BW therefore offering complete mechanical compatibility for parallel and series clamping.

VOLTAGE RATINGS

Type Number	Repetitive Peak Reverse Voltage V _{RRM} V	Conditions
DSF21545SV45	4500	$V_{RSM} = V_{RRM} + 100V$

Lower voltage grades available.

Outline type code: V. See Package Details for further information.

CURRENT RATINGS

Symbol	Parameter	Conditions	Max.	Units		
Double Sid	Double Side Cooled					
I _{F(AV)}	Mean forward current	Half wave resistive load, T _{case} = 65°C	3230	А		
I _{F(RMS)}	RMS value	$T_{\text{case}} = 65^{\circ}\text{C}$	5080	А		
I _F	Continuous (direct) forward current	$T_{\rm case} = 65^{\circ} C$	4680	А		
Single Side Cooled (Anode side)						
I _{F(AV)}	Mean forward current	Half wave resistive load, T _{case} = 65°C	2070	А		
I _{F(RMS)}	RMS value	$T_{\rm case} = 65^{\circ} C$	3255	А		
I _F	Continuous (direct) forward current	$T_{\text{case}} = 65^{\circ}\text{C}$	2875	А		

SURGE RATINGS

Symbol	Parameter	Conditions	Max.	Units
I _{FSM}	Surge (non-repetitive) forward current	10ms half sine; with 09/ V T = 150°C	20	kA
l ² t	I ² t for fusing	10ms half sine; with 0% V_{RRM} , $T_j = 150$ °C	2.0 x 10 ⁶	A ² s
I _{FSM}	Surge (non-repetitive) forward current	10mg half aings with E00/ V T 1E00C	16	kA
l ² t	I ² t for fusing	-10ms half sine; with 50% V_{RRM} , $T_j = 150$ °C	1.28 x 10 ⁶	A ² s
I _{FSM}	Surge (non-repetitive) forward current	10mg half sings with 1000/ \/ T	-	kA
l ² t	I ² t for fusing	-10ms half sine; with 100% V_{RRM} , $T_j = 150$ °C	-	A ² s

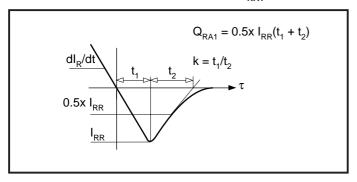
THERMAL AND MECHANICAL DATA

Symbol	Parameter	Conditions		Min.	Max.	Units
R _{th(j-c)}	Thermal resistance - junction to case	Double side cooled	dc	-	0.0075	°C/W
		Single side cooled	Anode dc	-	0.015	°C/W
			Cathode dc	-	0.015	°C/W
R _{th(c-h)}	Thermal resistance - case to heatsink	Clamping force 35.0kN with mounting compound	Double side	-	0.002	°C/W
			Single side	-	0.004	°C/W
T _{vj}	Virtual junction temperature	On-state (conducting)		-	150	°C
T _{stg}	Storage temperature range			-55	150	°C
-	Clamping force			34	48	kN

CHARACTERISTICS

Symbol	Parameter	Conditions	Тур.	Max.	Units
$V_{\scriptscriptstyle{\sf FM}}$	Forward voltage	At 3000A peak, T _{case} = 25°C	-	2.0	V
I _{RRM}	Peak reverse current	At V _{RRM} , T _{case} = 150°C	-	150	mA
t _{rr}	Reverse recovery time		7.0	-	μs
Q _{RA1}	Recovered charge (50% chord)	$I_F = 1000A$, $di_{RR}/dt = 100A/\mu s$	-	1800	μС
I _{RM}	Reverse recovery current	$T_{case} = 150^{\circ}C, V_{R} = 100V$	-	500	А
K	Soft factor		2	-	-
V_{TO}	Threshold voltage	At T _{vj} = 150°C	-	1.25	V
$r_{_{ m T}}$	Slope resistance	At T _{vj} = 150°C	-	0.25	mΩ
V_{FRM}	Forward recovery voltage	di/dt = 1000A/μs, T _j = 125°C	-	75	V

DEFINITION OF K FACTOR AND $\boldsymbol{Q}_{\text{RA1}}$



CURVES

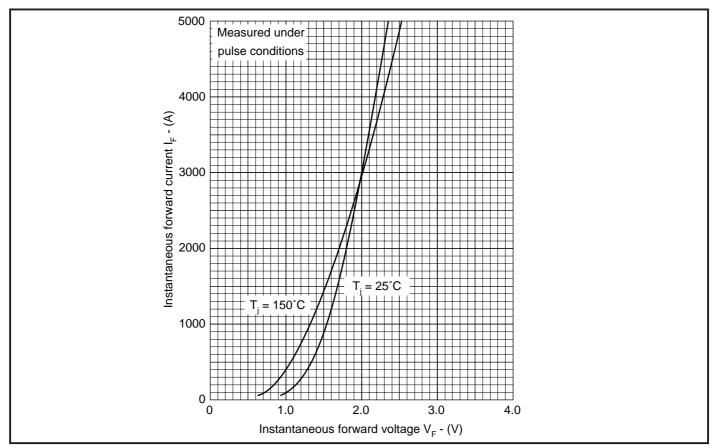


Fig.1 Maximum (limit) forward characteristics

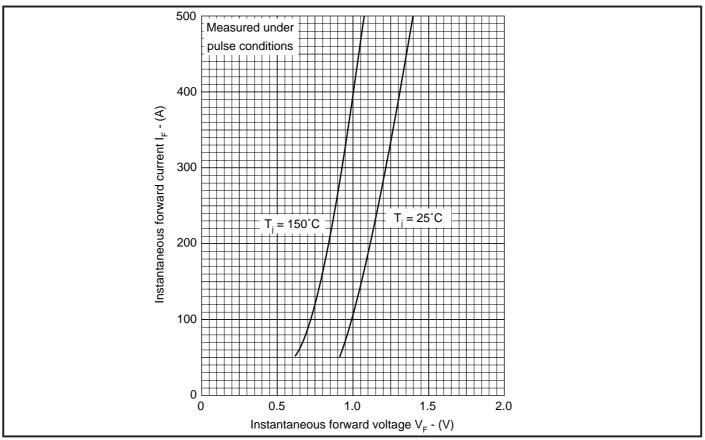


Fig.2 Maximum (limit) forward characteristics

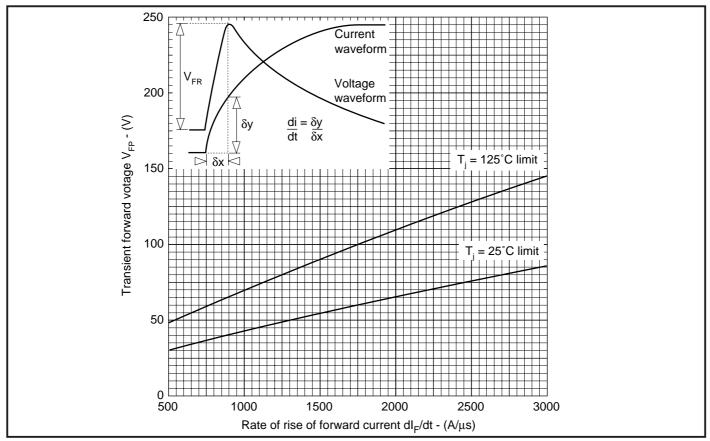


Fig.3 Transient forward voltage vs rate of rise of forward current

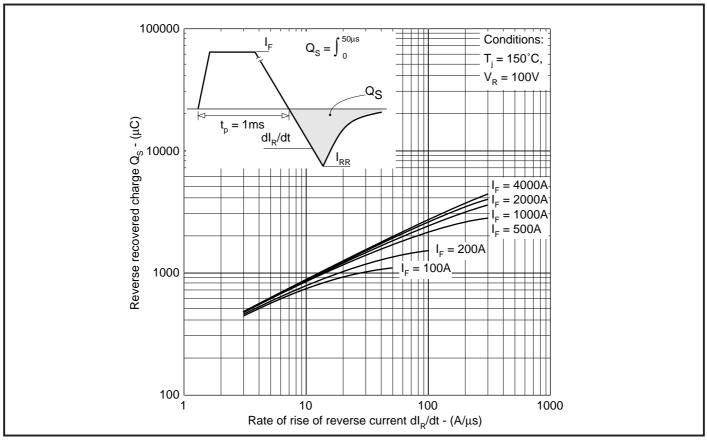


Fig.4 Recovered charge

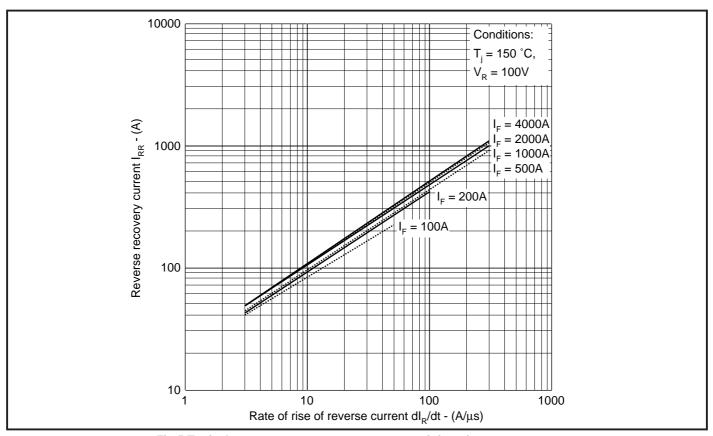


Fig.5 Typical reverse recovery current vs rate of rise of reverse current

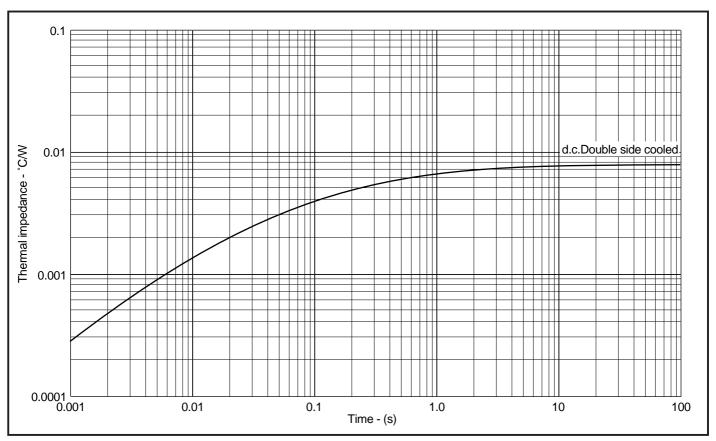
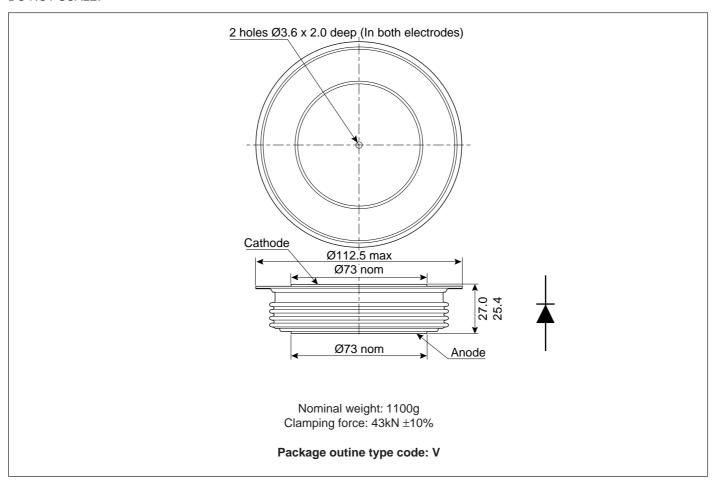


Fig.5 Maximum (limit) transient thermal impedance - junction to case

PACKAGE DETAILS

For further package information, please contact your local Customer Service Centre. All dimensions in mm, unless stated otherwise. DO NOT SCALE.



ASSOCIATED PUBLICATIONS

Title	Application Note	
	Number	
Calculating the junction temperature or power semiconductors	AN4506	
Recommendations for clamping power semiconductors	AN4839	
Thyristor and diode measurement with a multi-meter	AN4853	
Use of V _{TO} , r _T on-state characteristic	AN5001	

POWER ASSEMBLY CAPABILITY

The Power Assembly group was set up to provide a support service for those customers requiring more than the basic semiconductor, and has developed a flexible range of heatsink / clamping systems in line with advances in device types and the voltage and current capability of our semiconductors.

We offer an extensive range of air and liquid cooled assemblies covering the full range of circuit designs in general use today. The Assembly group continues to offer high quality engineering support dedicated to designing new units to satisfy the growing needs of our customers.

Using the up to date CAD methods our team of design and applications engineers aim to provide the Power Assembly Complete solution (PACs).

DEVICE CLAMPS

Disc devices require the correct clamping force to ensure their safe operation. The PACs range offers a varied selection of preloaded clamps to suit all of our manufactured devices. This include cube clamps for single side cooling of 'T' 22mm

Clamps are available for single or double side cooling, with high insulation versions for high voltage assemblies.

Please refer to our application note on device clamping, AN4839

HEATSINKS

Power Assembly has it's own proprietary range of extruded aluminium heatsinks. They have been designed to optimise the performance or our semiconductors. Data with respect to air natural, forced air and liquid cooling (with flow rates) is available on request.

For further information on device clamps, heatsinks and assemblies, please contact your nearest Sales Representative or the factory.



http://www.dynexsemi.com

e-mail: power_solutions@dynexsemi.com

HEADQUARTERS OPERATIONS DYNEX SEMICONDUCTOR LTD

Doddington Road, Lincoln. Lincolnshire. LN6 3LF. United Kingdom. Tel: 00-44-(0)1522-500500 Fax: 00-44-(0)1522-500550

DYNEX POWER INC.

Unit 7 - 58 Antares Drive, Nepean, Ontario, Canada K2E 7W6. Tel: 613.723.7035 Fax: 613.723.1518 Toll Free: 1.888.33.DYNEX (39639) CUSTOMER SERVICE CENTRES

France, Benelux, Italy and Spain Tel: +33 (0)1 69 18 90 00. Fax: +33 (0)1 64 46 54 50

North America Tel: 011-800-5554-5554. Fax: 011-800-5444-5444

UK, Germany, Scandinavia & Rest Of World Tel: +44 (0)1522 500500. Fax: +44 (0)1522 500020

SALES OFFICES

France, Benelux, Italy and Spain Tel: +33 (0)1 69 18 90 00. Fax: +33 (0)1 64 46 54 50 Germany Tel: 07351 827723

North America Tel: (613) 723-7035. Fax: (613) 723-1518. Toll Free: 1.888.33.DYNEX (39639) / Tel: (831) 440-1988. Fax: (831) 440-1989 / Tel: (949) 733-3005. Fax: (949) 733-2986.

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Preliminary Information: The product is in design and development. The datasheet represents the product as it is understood but details may change.

Advance Information: The product design is complete and final characterisation for volume production is well in hand.

No Annotation: The product parameters are fixed and the product is available to datasheet specification.

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